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UF5400GP THRU UF5408GP

Features

- Lead Free Finish/RoHS Compliant(Note 1) ("P" Suffix designates RoHS Compliant. See ordering information)
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1
- Glass Passivated Junction
- Low Forward Voltage Drop and High Surge Capability
- Ultra Fast Switching Speed For High Efficiency

Maximum Ratings

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Typical Thermal Resistance 20°C/W

Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
UF5400GP	---	50V	35V	50V
UF5401GP	---	100V	70V	100V
UF5402GP	---	200V	140V	200V
UF5404GP	---	400V	280V	400V
UF5406GP	---	600V	420V	400V
UF5407GP	---	800V	560V	800V
UF5408GP	---	1000V	700V	1000V

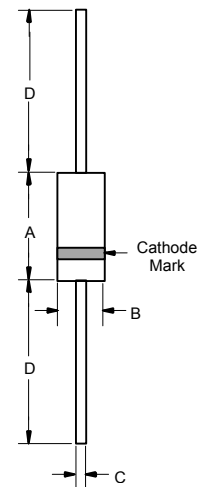
Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	3 A	$T_A = 55^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	100A	8.3ms, half sine
Maximum Instantaneous Forward Voltage UF5400GP-5402GP UF5404GP UF5406GP-5408GP	V_F	1.0V 1.3V 1.7V	$I_{FM} = 3.0\text{A};$ $T_A = 25^\circ\text{C}$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	10 μA 50 μA	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$
Maximum Reverse Recovery Time UF5400GP-5404GP UF5406GP-5408GP	T_{rr}	50ns 75ns	$I_F=0.5\text{A}, I_R=1.0\text{A},$ $I_{rr}=0.25\text{A}$
Typical Junction Capacitance UF5400GP-5404GP UF5406GP-5408GP	C_J	75pF 50pF	Measured at 1.0MHz, $V_R=4.0\text{V}$

Notes:1.High Temperature Solder Exemption Applied, see EU Directive Annex 7.

3 Amp Ultra Fast Glass Passivated Recovery Rectifier 50 to 1000 Volts

DO-201AD

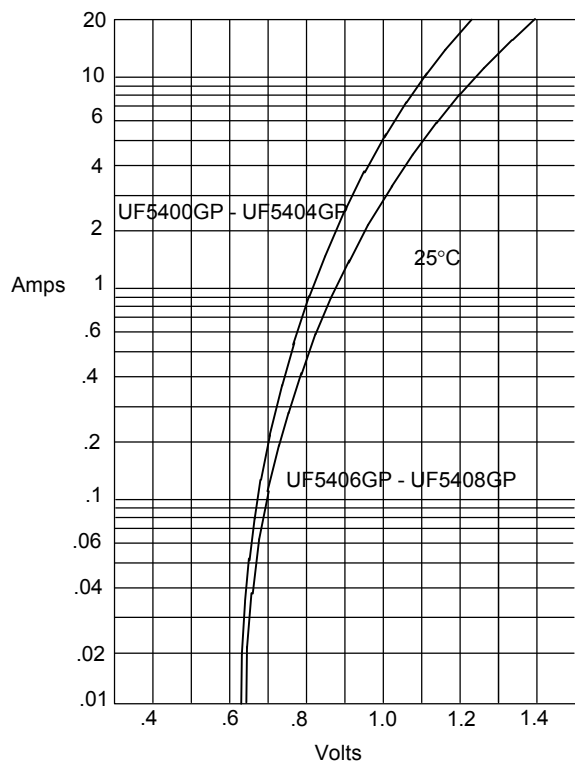


DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.287	.374	7.30	9.50	
B	.189	.208	4.80	5.30	
C	.048	.052	1.20	1.30	
D	1.000	—	25.40	—	

UF5400GP thru UF5408GP

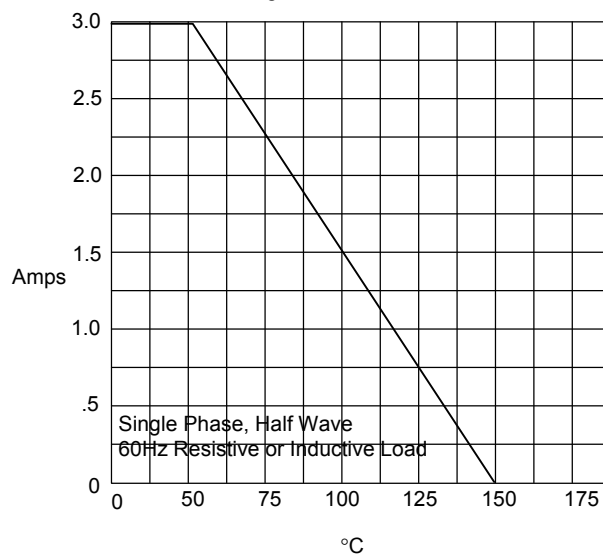


Figure 1
Typical Forward Characteristics



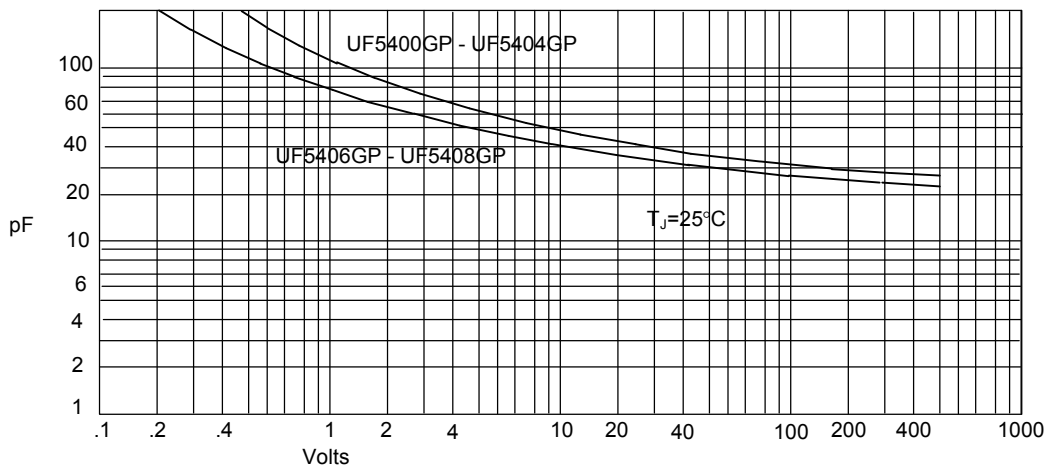
Instantaneous Forward Current - Amperes *versus*
Instantaneous Forward Voltage - Volts

Figure 2
Forward Derating Curve



Average Forward Rectified Current - Amperes *versus*
Ambient Temperature - °C

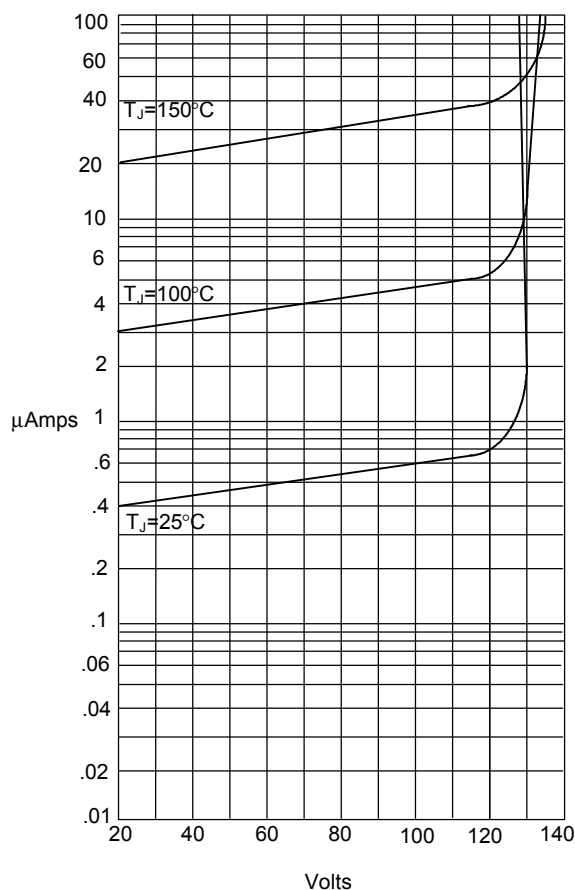
Figure 3
Junction Capacitance



Junction Capacitance - pF *versus*
Reverse Voltage - Volts

UF5400GP thru UF5408GP

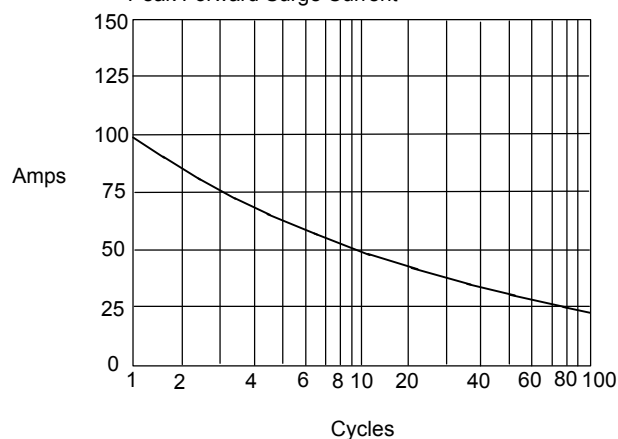
Figure 4
Typical Reverse Characteristics



Instantaneous Reverse Leakage Current - MicroAmperes versus
Percent Of Rated Peak Reverse Voltage - Volts

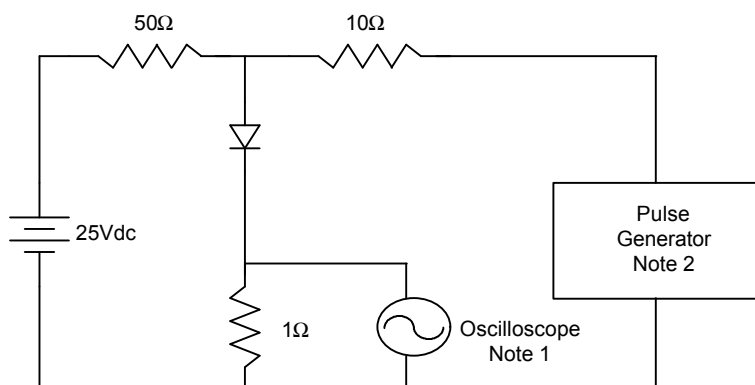


Figure 5
Peak Forward Surge Current



Peak Forward Surge Current - Amperes versus
Number Of Cycles At 60Hz - Cycles

Figure 6
Reverse Recovery Time Characteristic And Test Circuit Diagram



Notes:

1. Rise Time = 7ns max.
Input impedance = 1 megohm, 22pF
2. Rise Time = 10ns max.
Source impedance = 50 ohms
3. Resistors are non-inductive

